

General Description

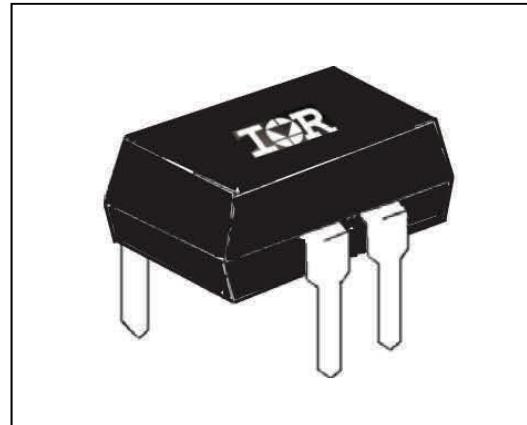
The PVI Series Photovoltaic Isolator generates an electrically isolated DC voltage upon receipt of a DC input signal. It is capable of directly driving gates of power MOSFETs or IGBTs. It utilizes a monolithic integrated circuit photovoltaic generator of novel construction as its output. The output is controlled by radiation from a GaAlAs light emitting diode (LED), which is optically isolated from the photovoltaic generator.

The PVI Series is ideally suited for applications requiring high-current and/or high-voltage switching with optical isolation between the low-level driving circuitry and high-energy or high-voltage load circuits. It can be used for directly driving gates of power MOSFETs. The dual-channel device allows its outputs to drive independent discrete power MOSFETs, or be connected in parallel or in series to provide higher current drive for power MOSFETs or higher voltage drive for IGBTs. The PVI Series Photovoltaic isolators employ fast turn-off circuitry.

These PVI Series Photovoltaic Isolators are packaged in 8-pin, molded DIP packages and available with either thru-hole or surface-mount ("gull-wing") leads, in plastic shipping tubes.

Features

- Isolated Voltage Source
- Monolithic Construction
- Up to 8 μ A Output
- Single Output
- Solid-State Reliability



Part Identification

PVI5080NPbF	thru-hole
PVI5080NSPbF	Surface-mount (gull-wing)

Applications

- Load Distribution
- Industrial Controls
- Current-to-Voltage Conversion
- Custom Solid-State Relay

Electrical Specifications (-40°C ≤ T_A ≤ +85°C unless otherwise specified)

INPUT CHARACTERISTICS	Limits	Units
Input Current Range (see figure 4)	2.0 to 50	mA (DC)
Maximum Forward Voltage Drop @ 10mA, 25°C (see figure 5)	1.4	V (DC)
Maximum Reverse Voltage	6.0	V (DC)
Maximum Reverse Current @ -6.0V (DC), 25°C	100	µA (DC)
Maximum Pulsed Input Current @ 25°C (see figure 6)	1.0	A (peak)

OUTPUT CHARACTERISTICS	Limits	Units
Maximum Forward Voltage @ 10µA	8.0 per channel	V _(DC)
Maximum Reverse Current @ -10V _{DC}	10	µA (DC)

COUPLED CHARACTERISTICS	Limits	Units
Minimum Open Circuit Voltage @ ILED = 10mA, 25°C, RL = >10MΩ (see figures 1 to 2)	5.0	V _(DC)
Minimum Short Circuit Current @ ILED = 14mA, 25°C (see figures 1 to 2)	8.0	µA (DC)
Maximum Capacitance (Input/Output)	1.0	pF
Maximum Ton Time @ ILED=10mA, CLOAD=10pF (See Figure7)	300	µS
RL > 20MΩ	160	µS
RL=10MΩ	90	µS
RL=4.7MΩ	220	µS
Maximum Toff Time @ ILED=10mA, CLOAD=10pF (See Figure7)		

GENERAL CHARACTERISTICS	Limits	Units
Minimum Dielectric Strength, Input-Output	4000	V _{RMS}
Minimum Dielectric Strength, Output-to-Output	1200	V _{DC}
Minimum Insulation Resistance, Input-to-Output, @T _A =+25°C, 50%RH, 100V _{DC}	10 ¹²	Ω
Maximum Pin Soldering Temperature (10 seconds maximum)	+260	
Ambient Temperature Range: Operating	-40 to 85	°C
Storage	-40 to 125	

Infineon Technology does not recommend the use of this product in aerospace, avionics, military or life support applications. Users of this Infineon Technology product in such applications assume all risks of such use and indemnify Infineon Technology against all damages resulting from such use.

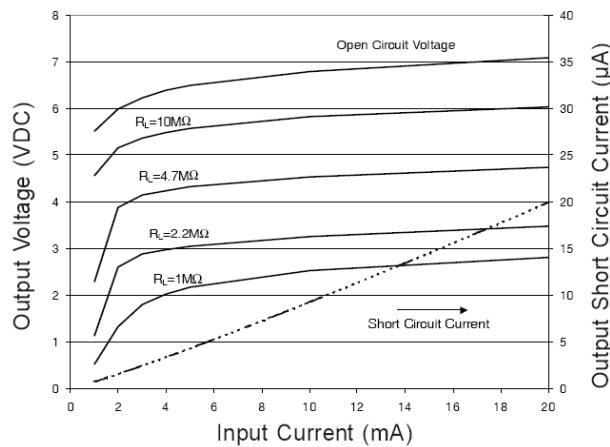


Figure 1. Typical Output Characteristics

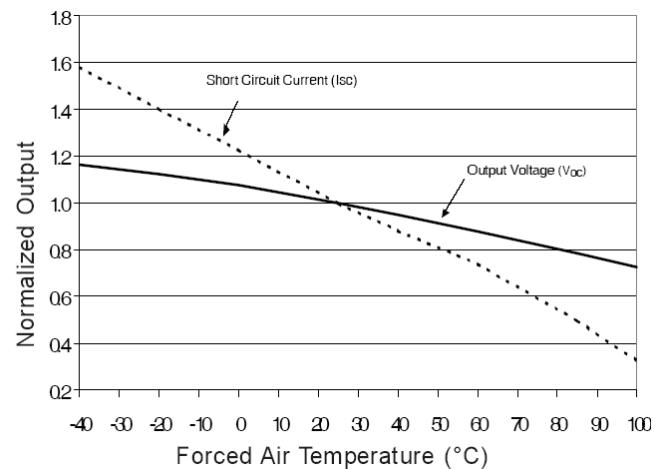


Figure 2. Typical Variation of Output

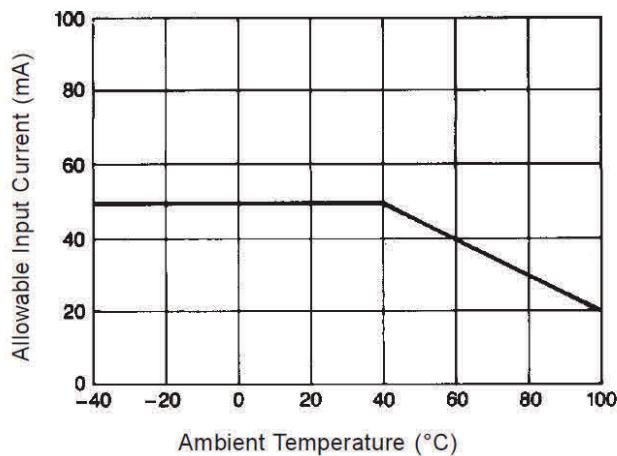


Figure 3. Input Current Derating

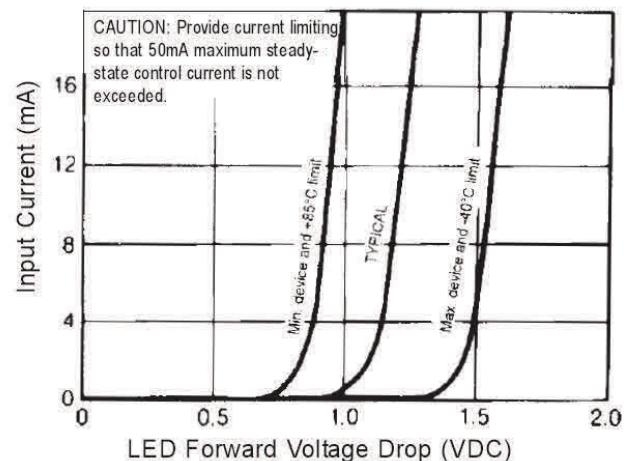


Figure 4. Input Characteristics

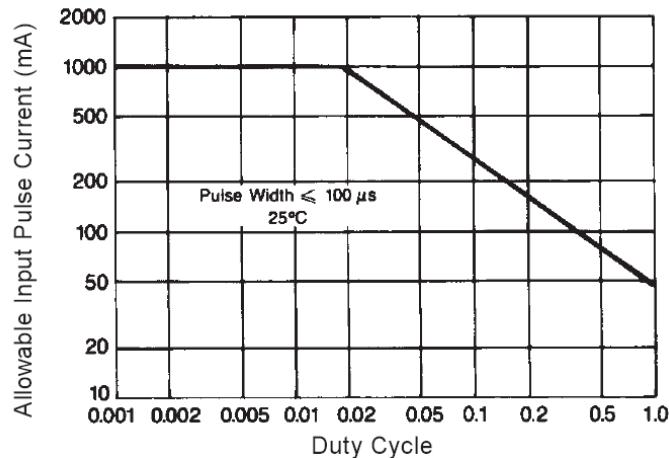


Figure 5. Input Pulse Capability

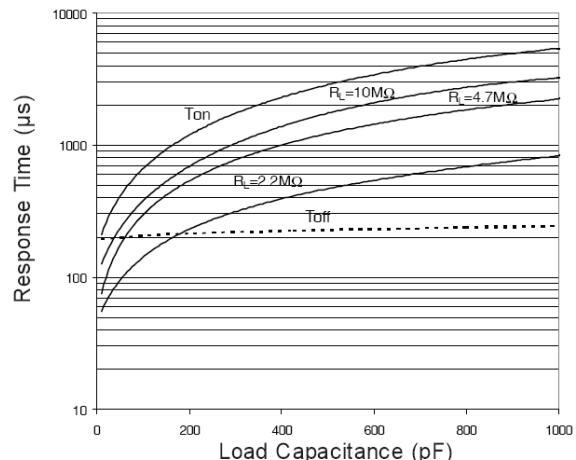
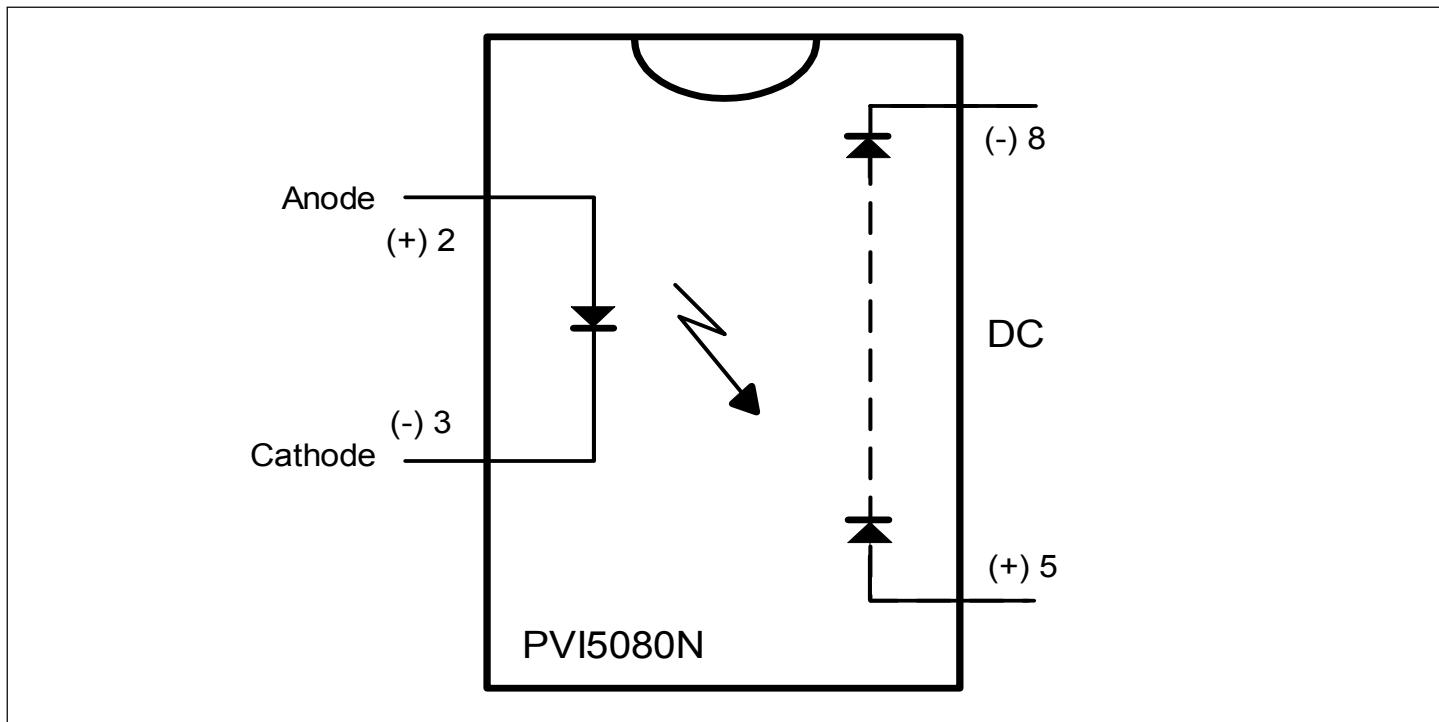
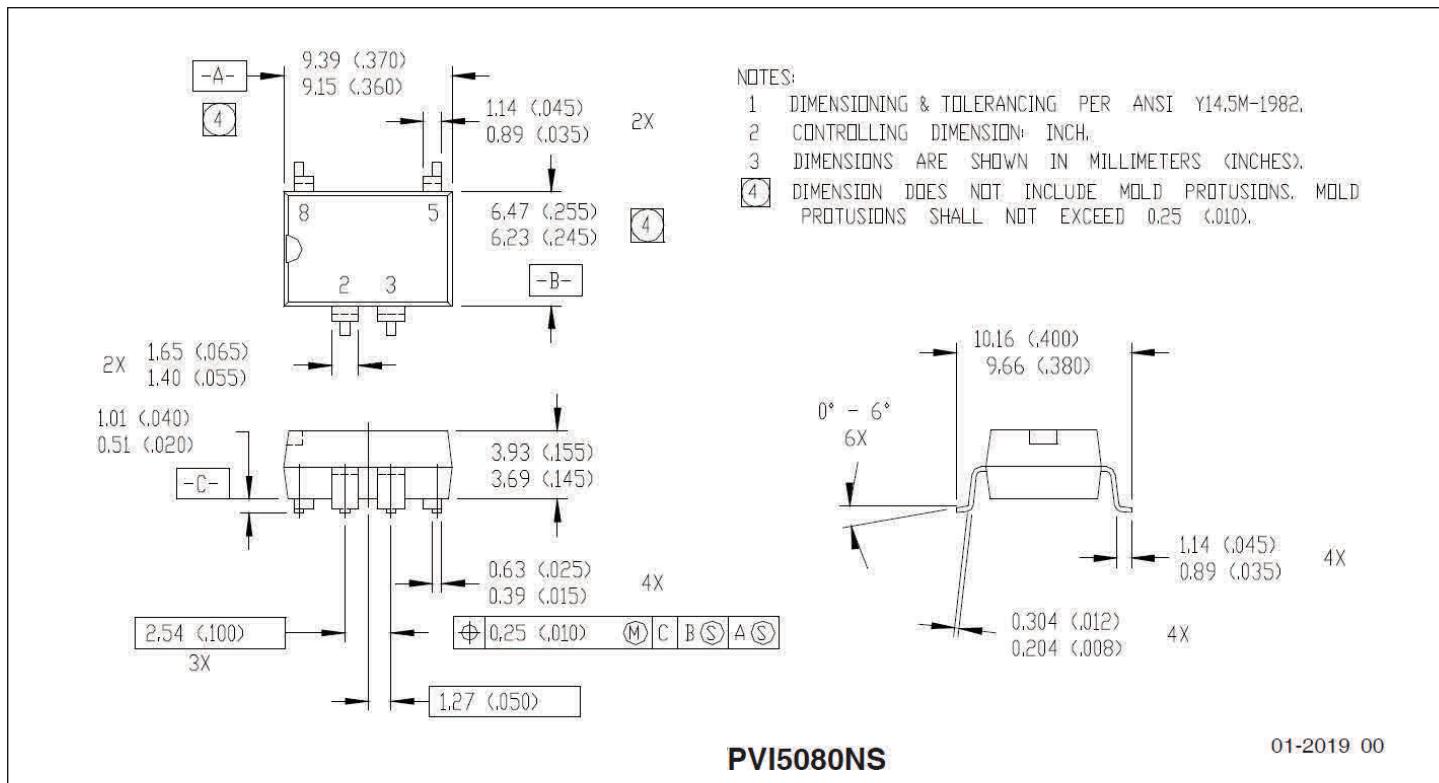
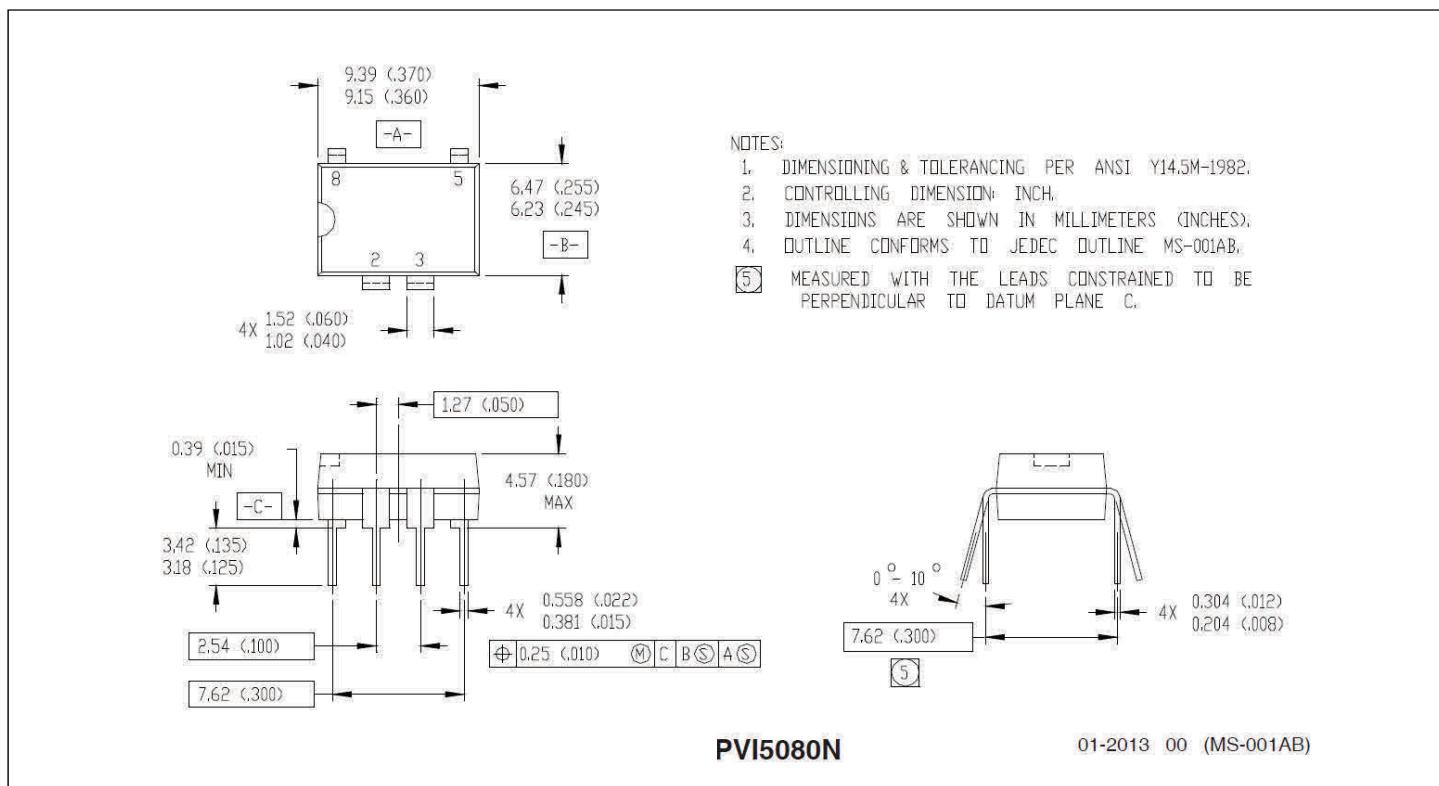


Figure 6. Typical Response Time

Wiring Diagram



Case Outlines



Qualification Information

Qualification Level	Industrial (per JEDEC JESD47F [†] guidelines)	
Moisture Sensitivity Level	PVI5080NPbF	N/A
	PVI5080NSPbF	MSL4 (per JEDEC J-STD-020E & JEDEC J-STD-033C) [†]
RoHS Compliant	Yes	

[†] Applicable version of JEDEC standard at the time of product release.